

# Plastic Medium Power NPN Silicon Transistor

**BD159**

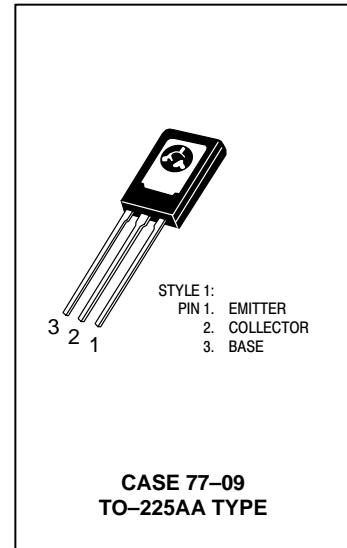
... designed for power output stages for television, radio, phonograph and other consumer product applications.

- Suitable for Transformerless, Line-Operated Equipment
- Thermopad™ Construction Provides High Power Dissipation Rating for High Reliability

**0.5 AMPERE  
POWER TRANSISTOR  
NPN SILICON  
350 VOLTS  
20 WATTS**

## MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Collector–Emitter Voltage	$V_{CEO}$	350	Vdc
Collector–Base Voltage	$V_{CB}$	375	Vdc
Emitter–Base Voltage	$V_{EB}$	5.0	Vdc
Collector Current — Continuous Peak	$I_C$	0.5 1.0	Adc
Base Current	$I_B$	0.25	Adc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	20 0.16	Watts W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-65 to +150	$^\circ\text{C}$



## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$\theta_{JC}$	6.25	$^\circ\text{C}/\text{W}$

## ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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## OFF CHARACTERISTICS

Collector–Emitter Sustaining Voltage ( $I_C = 1.0 \text{ mAdc}, I_B = 0$ )	$BV_{CEO}$	350	—	Vdc
Collector Cutoff Current (At rated voltage)	$I_{CBO}$	—	100	$\mu\text{Adc}$
Emitter Cutoff Current ( $V_{EB} = 5.0 \text{ Vdc}, I_C = 0$ )	$I_{EBO}$	—	100	$\mu\text{Adc}$

## ON CHARACTERISTICS

DC Current Gain ( $I_C = 50 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}$ )	$h_{FE}$	30	240	—
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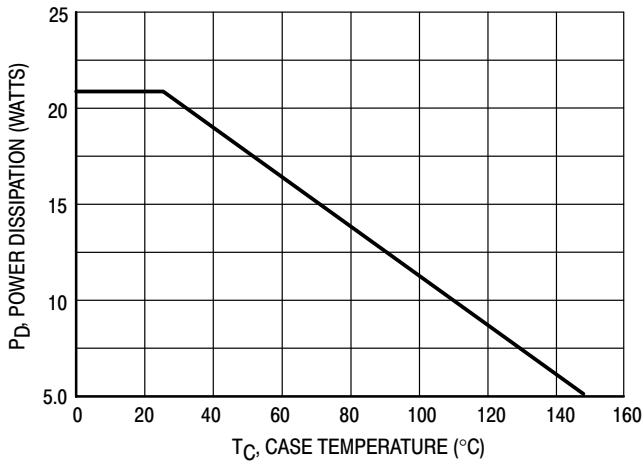


Figure 1. Power-Temperature Derating Curve

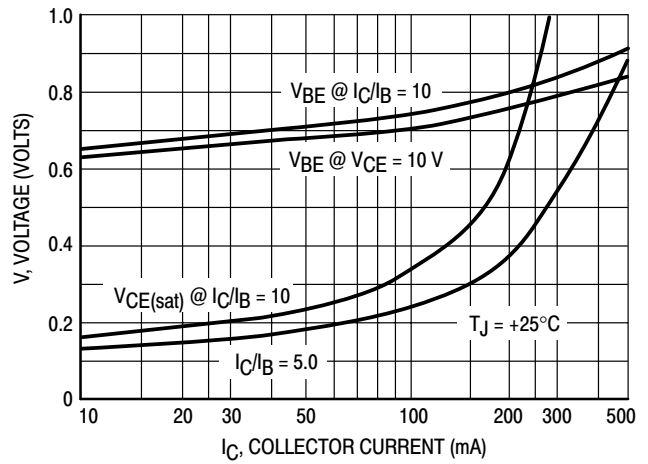


Figure 2. "On" Voltages

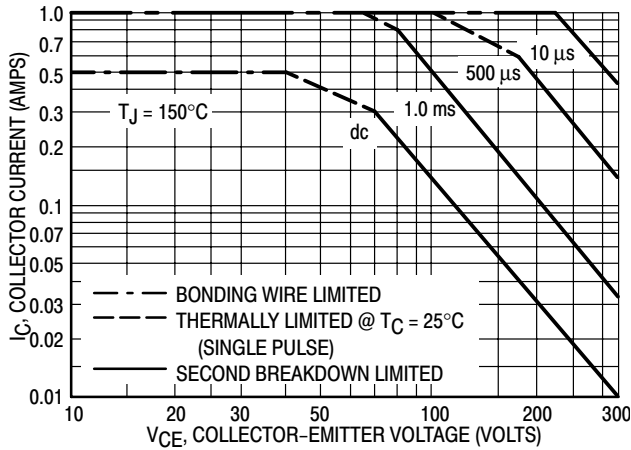


Figure 3. DC Safe Operating Area

The Safe Operating Area Curves indicate  $I_C - V_{CE}$  limits below which the device will not enter secondary breakdown. Collector load lines for specific circuits must fall within the applicable Safe Area to avoid causing a catastrophic failure. To insure operation below, the maximum  $T_J$ , power-temperature derating must be observed for both steady state and pulse power conditions.

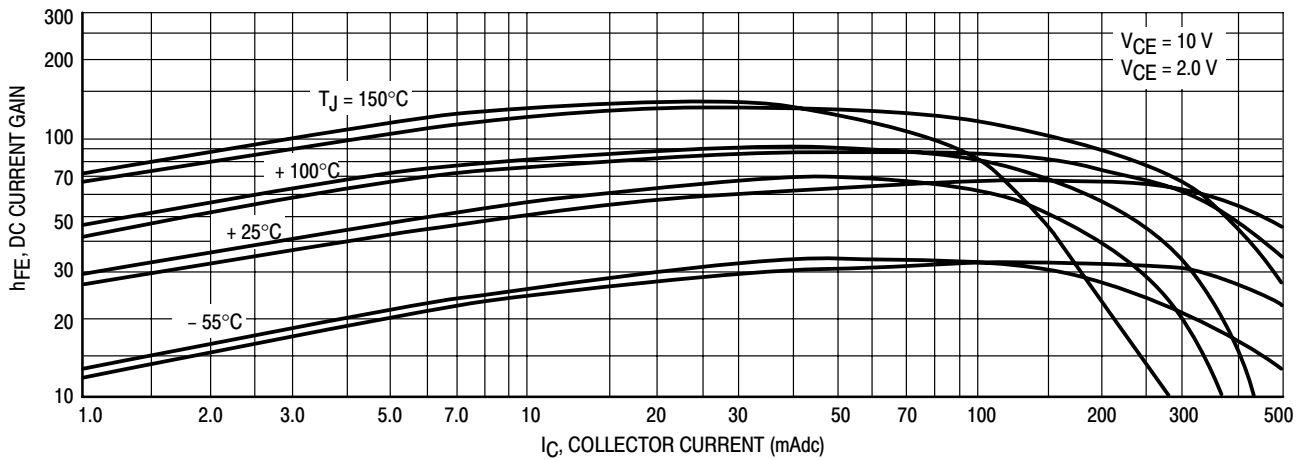
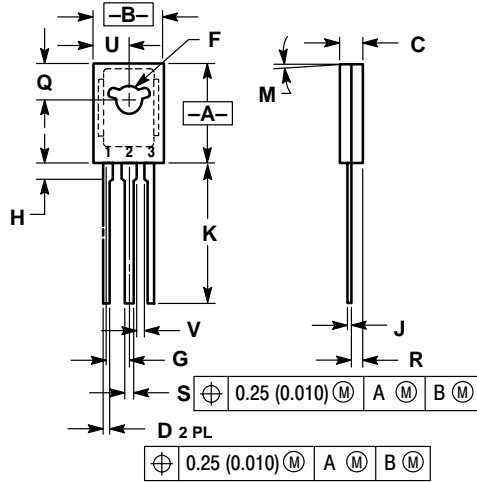


Figure 4. Current Gain

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## PACKAGE DIMENSIONS

### CASE 77-09 TO-225AA TYPE ISSUE W



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.425	0.435	10.80	11.04
B	0.295	0.305	7.50	7.74
C	0.095	0.105	2.42	2.66
D	0.020	0.026	0.51	0.66
F	0.115	0.130	2.93	3.30
G	0.094 BSC		2.39 BSC	
H	0.050	0.095	1.27	2.41
J	0.015	0.025	0.39	0.63
K	0.575	0.655	14.61	16.63
M	5° TYP		5° TYP	
Q	0.148	0.158	3.76	4.01
R	0.045	0.065	1.15	1.65
S	0.025	0.035	0.64	0.88
U	0.145	0.155	3.69	3.93
V	0.040	---	1.02	---

- STYLE 1:  
PIN 1. EMITTER  
2. COLLECTOR  
3. BASE

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